# SN74F125 QUADRUPLE BUS BUFFER GATE WITH 3-STATE OUTPUTS

SDFS016B - JANUARY 1989 - REVISED JULY 2002

### 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers

## description/ordering information

The SN74F125 features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable  $(\overline{OE})$  input is high.

1OE   1   14   V <sub>CC</sub> 1A   2   13   4OE     1Y   3   12   4A     2OE   4   11   4Y     2A   5   10   3OE     2Y   6   9   3A     GND   7   8   3Y	D, DB, N, OR NS PACKAGE (TOP VIEW)										
	1A [ 1Y [ 2OE [ 2A [ 2Y [	3 4 5 6	13 12 11 10	40E 4A 4Y 30E 3A							

	TA	PACK	AGE <sup>†</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING							
		PDIP – N Tube		SN74F125N	SN74F125N							
		SOIC – D	Tube	SN74F125D	E105							
	0°C to 70°C	3010 - D	Tape and reel	SN74F125DR	F125							
		SOP – NS	Tape and reel	SN74F125NSR	74F125							
		SSOP – DB	Tape and reel	SN74F125DBR	F125							

# ORDERING INFORMATION

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (each buffer)									
INPUTS OUTPUT									
OE	Α	Y							
L	Н	Н							
L	L	L							
н	Х	Z							



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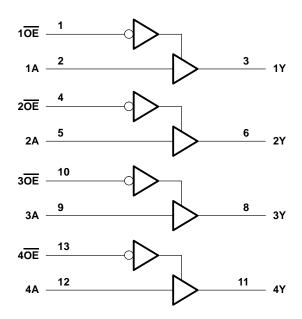


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## logic diagram (positive logic)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Input voltage range, V <sub>I</sub> (see Note 1) Input current range Voltage range applied to any output in the disable Voltage range applied to any output in the high st Current into any output in the low state Package thermal impedance, $\theta_{JA}$ (see Note 2): D	-0.5 V to 7 V -1.2 V to 7 V -30 mA to 5 mA ed or power-off state0.5 V to 5.5 V tate
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input voltage ratings may be exceeded provided the input current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

## recommended operating conditions (see Note 3)

		MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5	5.5	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
Iк	Input clamp current			-18	mA
ЮН	High-level output current			- 15	mA
IOL	Low-level output current			64	mA
Т <sub>А</sub>	Operating free-air temperature	0		70	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	-	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	lı = – 18 mA			-1.2	V
	V <sub>CC</sub> = 4.5 V	I <sub>OH</sub> = – 3 mA	2.4	3.3		
VOH	VCC = 4.5 V	I <sub>OH</sub> = – 15 mA	2	3.1		V
	V <sub>CC</sub> = 4.75 V,	I <sub>OH</sub> = – 3 mA	2.7			
V <sub>OL</sub>	V <sub>CC</sub> = 4.5 V,	I <sub>OL</sub> = 64 mA		0.4	0.55	V
lı	$V_{CC} = 0,$	V <sub>I</sub> = 7 V			0.1	mA
Чн	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 2.7 V			20	μΑ
IIL	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.5 V			-20	μΑ
IOZH	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V			50	μΑ
IOZL	V <sub>CC</sub> = 5.5 V,	$V_{O} = 0.5 V$			-50	μΑ
los‡	V <sub>CC</sub> = 5.5 V,	VO = 0	-100		-225	mA
ІССН	V <sub>CC</sub> = 5.5 V,	Outputs open		17	24	mA
ICCL	V <sub>CC</sub> = 5.5 V,	Outputs open		28	40	mA
ICCZ	V <sub>CC</sub> = 5.5 V,	Outputs open		25	35	mA

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.
<sup>‡</sup> Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.

### switching characteristics (see Figure 1)

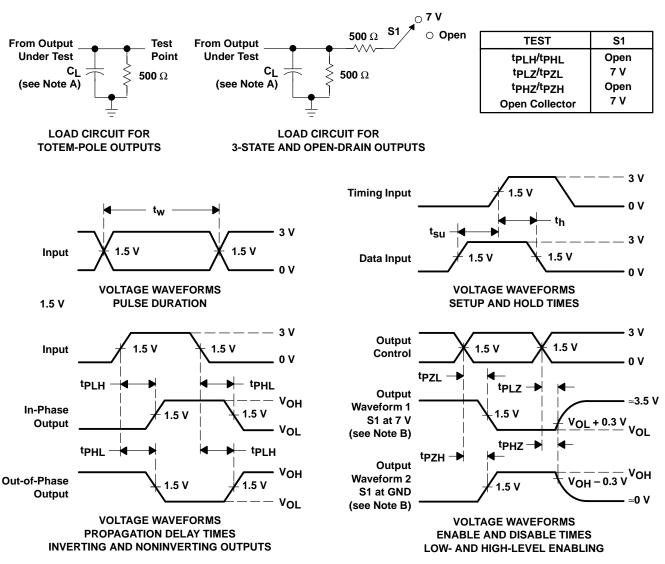
PARAMETER	FROM (INPUT)	TO (OUTPUT)	CI RI	CC = 5 V _ = 50 pl _ = 500 s _ = 25°C	<b>F,</b> Ω,	V <sub>CC</sub> = 4.5 C <sub>L</sub> = 50 pF R <sub>L</sub> = 500 G T <sub>A</sub> = MIN t	; 2,	UNIT
			MIN	TYP	MAX	MIN	MAX	
<sup>t</sup> PLH	А	V	1.2	3.6	6	1.2	6.5	ns
<sup>t</sup> PHL	A	Ŷ	2.2	5.1	7.5	2.2	8	115
<sup>t</sup> PZH	ŌĒ	V	2.7	5.1	7.5	2.7	8.5	ns
<sup>t</sup> PZL	UE	ř	3.2	5.6	8	3.2	9	115
<sup>t</sup> PHZ	ŌĒ	V	1	3.1	5	1	6	
<sup>t</sup> PLZ	UL UL	1	1	3.1	5.5	1	6	ns

§ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



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PARAMETER MEASUREMENT INFORMATION

- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns, duty cycle = 50%.
  - D. The outputs are measured one at a time with one input transition per measurement.

#### Figure 1. Load Circuit and Voltage Waveforms



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### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74F125D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74F125DE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74F125DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74F125DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74F125DRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74F125DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74F125N	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74F125NE4	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74F125NSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74F125NSRE4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

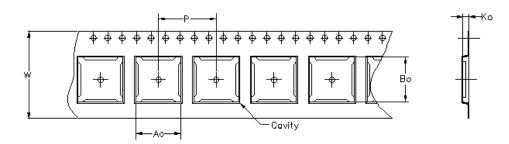
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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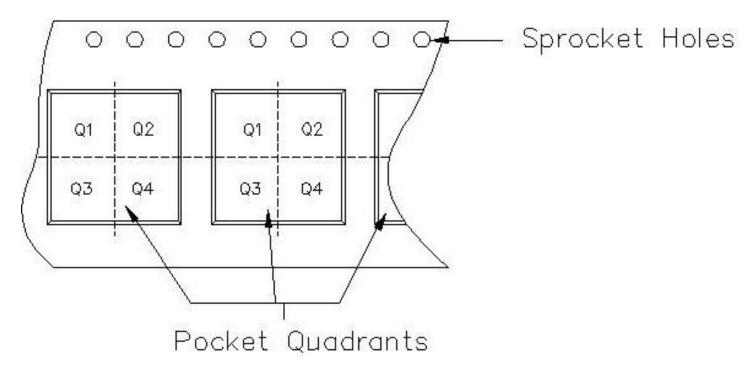


19-May-2007



Carrier tape design is defined largely by the component lentgh, width, and thickness.

Ao =	Dimension	designed	to	accommodate	the	component	width.		
Bo =	Dimension	designed	to	accommodate	the	component	length.		
Ko =	Dímension	designed	to	accommodate	the	component	thickness.		
W = 1	Overall widt	h of the	car	rier tape.					
P = f	P = Pitch between successive cavity centers.								



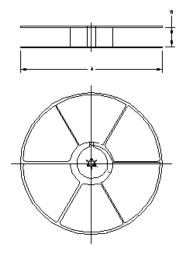
TAPE AND REEL INFORMATION

# PACKAGE MATERIALS INFORMATION



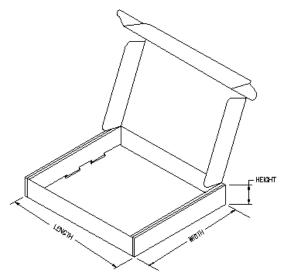
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Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74F125DR	D	14	MLA	330	16	6.5	9.0	2.1	8	16	Q1
SN74F125NSR	NS	14	MLA	330	16	8.2	10.5	2.5	12	16	Q1



# TAPE AND REEL BOX INFORMATION

Device	Package	Package Pins Site		Length (mm)	Width (mm)	Height (mm)	
SN74F125DR	D	14	MLA	342.9	336.6	28.58	
SN74F125NSR	NS	14	MLA	342.9	336.6	28.58	



# N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



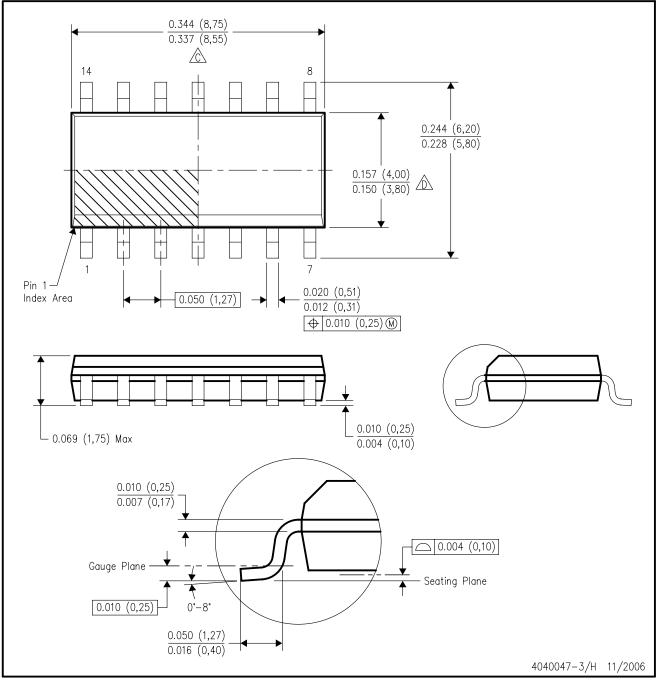
NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AB.



## MECHANICAL DATA

### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.







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